Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π–MOSV)

2SK2967

DC-DC Converter, Relay Drive and Motor Drive Applications

• Low drain-source ON resistance : $R_{DS (ON)} = 48 \text{ m}\Omega \text{ (typ.)}$

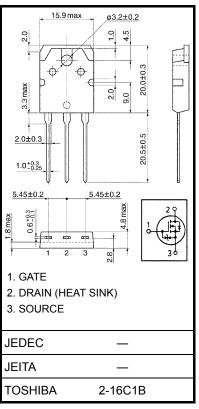
• High forward transfer admittance : $|Y_{fs}| = 30 \text{ S (typ.)}$

Low leakage current : I_{DSS} = 100 μA (max) (V_{DS} = 250 V)

• Enhancement mode : $V_{th} = 1.5 \text{ to } 3.5 \text{ V } (V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA})$

Absolute Maximum Ratings (Ta = 25°C)

| Characteris | stics | Symbol | Rating | Unit | |
|-------------------------|------------------------|------------------|------------|------|--|
| Drain-source voltage | | V_{DSS} | 250 | V | |
| Drain-gate voltage (Ro | _{SS} = 20 kΩ) | V_{DGR} | 250 | V | |
| Gate-source voltage | | V _{GSS} | ±20 | V | |
| Drain current | DC (Note 1) | ΙD | 30 | Α | |
| | Pulse (Note 1) | I _{DP} | 120 | Α | |
| Drain power dissipation | n (Tc = 25°C) | P _D | 150 | W | |
| Single pulse avalanche | e energy (Note 2) | E _{AS} | 925 | mJ | |
| Avalanche current | | I _{AR} | 30 | Α | |
| Repetitive avalanche e | nergy (Note 3) | E _{AR} | 15 | mJ | |
| Channel temperature | | T _{ch} | 150 | °C | |
| Storage temperature ra | ange | T _{stg} | -55 to 150 | °C | |



Weight: 4.6 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|--|------------------------|-------|------|
| Thermal resistance, channel to case | R _{th (ch-c)} | 0.833 | °C/W |
| Thermal resistance, channel to ambient | R _{th (ch-a)} | 50 | °C/W |

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 50 V, T_{ch} = 25°C (initial), L = 1.74 mH, I_{AR} = 30 A, R_G = 25 Ω

Note 3: Repetitive rating: pulse width limited by maximum channel temperature.

This transistor is an electrostatic-sensitive device.

Please handle with caution.

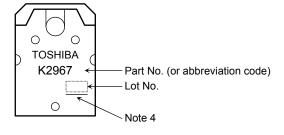
Electrical Characteristics (Ta = 25°C)

| Charac | eteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|------------------------|----------------------|--|------|------|-----|------|
| Gate leakage cu | rrent | I _{GSS} | V _{GS} = ±16 V, V _{DS} = 0 V | _ | _ | ±10 | μA |
| Drain cut-off cui | rent | I _{DSS} | V _{DS} = 250 V, V _{GS} = 0 V | _ | _ | 100 | μA |
| Drain-source br | eakdown voltage | V (BR) DSS | I _D = 10 mA, V _{GS} = 0 V | 250 | _ | _ | V |
| Gate threshold v | roltage | V _{th} | V _{DS} = 10 V, I _D = 1 mA | 1.5 | _ | 3.5 | V |
| Drain-source Ol | N resistance | R _{DS} (ON) | V _{GS} = 10 V, I _D = 15 A | _ | 48 | 68 | mΩ |
| Forward transfer | admittance | Y _{fs} | V _{DS} = 10 V, I _D = 15 A | 15 | 30 | _ | S |
| Input capacitano | e | C _{iss} | | _ | 5400 | _ | pF |
| Reverse transfer | capacitance | C _{rss} | V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz | _ | 580 | _ | |
| Output capacitar | tance C _{oss} | | _ | 1900 | _ | 1 | |
| Switching time - | Rise time | t _r | $V_{GS} \stackrel{10V}{\underset{OV}{\text{OV}}} \stackrel{I_{D}=15\text{A}}{\underset{R_{L}=}{\text{CS}}} V_{OUT}$ $V_{DD} \stackrel{\vdots}{=} 100V$ | _ | 20 | _ | ns |
| | Turn-on time | t _{on} | | _ | 50 | _ | |
| | Fall time | t _f | | _ | 35 | _ | |
| | Turn-off time | t _{off} | Duty $\leq 1\%$, $t_w = 10 \mu s$ | _ | 200 | _ | |
| Total gate charge (gate-source plus gate-drain) | | Qg | $V_{DD} \approx 200 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}$ | | 132 | _ | |
| Gate-source charge | | Q _{gs} | | | 80 | | nC |
| Gate-drain ("miller") Charge | | Q _{gd} | | | 52 | | |

Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|------------------|---|-----|------|------|------|
| Continuous drain reverse current (Note 1) | I _{DR} | _ | _ | _ | 30 | Α |
| Pulse drain reverse current (Note 1) | I _{DRP} | _ | _ | _ | 120 | Α |
| Forward voltage (diode) | V _{DSF} | I _{DR} = 30 A, V _{GS} = 0 V | _ | _ | -2.0 | V |
| Reverse recovery time | t _{rr} | I _{DR} = 30 A, V _{GS} = 0 V | _ | 270 | _ | ns |
| Reverse recovery charge | Q _{rr} | dl _{DR} / dt = 100 A / μs | _ | 3.0 | _ | μC |

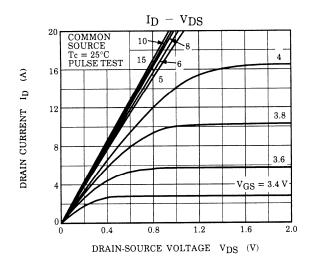
Marking

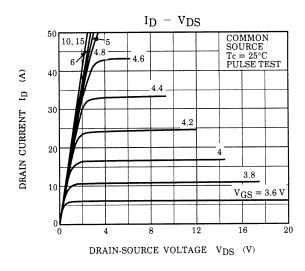


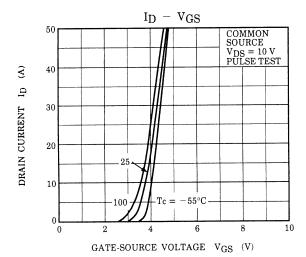
Note 4: A line under a Lot No. identifies the indication of product Labels.

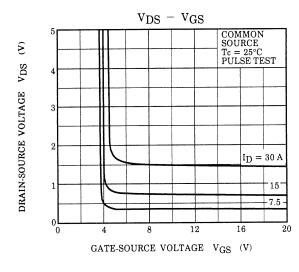
Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

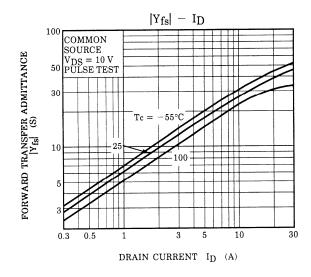
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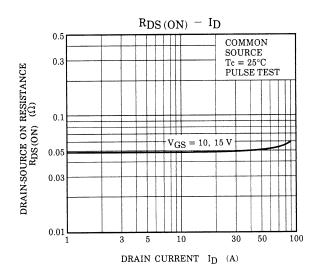


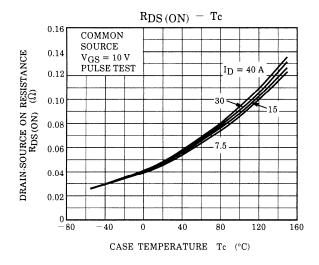


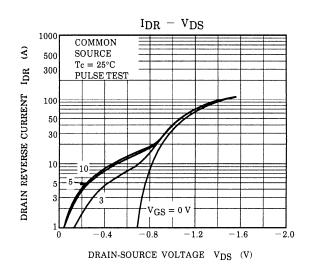


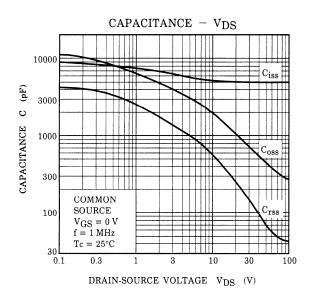


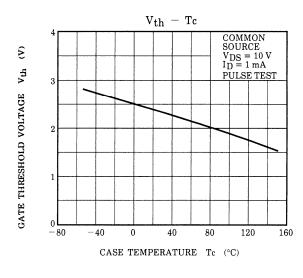


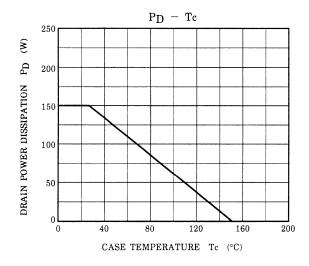


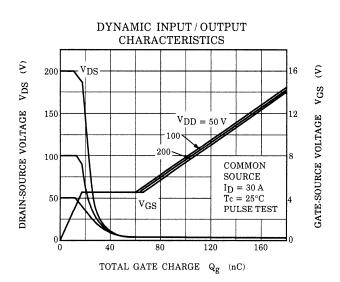




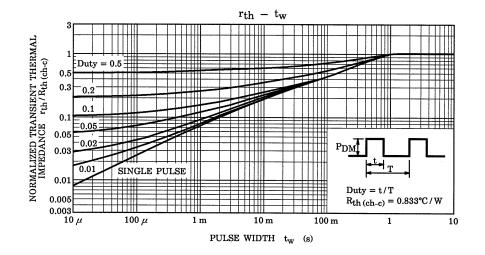


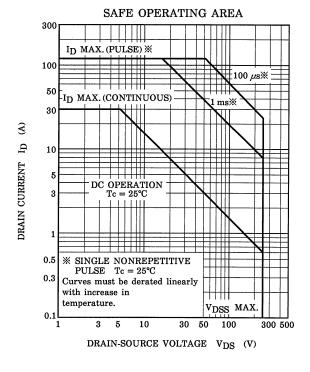


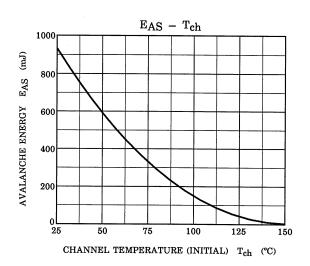


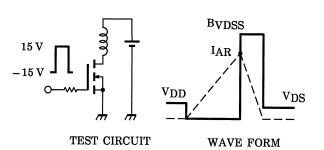


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$$\begin{aligned} &R_G = 25~\Omega \\ &V_{DD} = 50~V,~L = 1.74~mH \end{aligned} \qquad E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{BVDSS}{BVDSS - V_{DD}} \right) \end{aligned}$$

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